

# 1.0MHz, 2A Synchronous Step-Down Converter

# **FEATURES**

- High Efficiency: Up to 96%(@3.3V)
- . 1.0MHz Constant Frequency Operation
- . 2A Output Current
- . No Schottky Diode Required
- . 2.5V to 6V Input Voltage Range
- . Output Voltage as Low as 0.6V
- PFM Mode for High Efficiency in Light Load
- . 100% Duty Cycle in Dropout Operation
- . Low Quiescent Current: 40µA
- . Short Circuit Protection
- . Thermal Fault Protection
- . Inrush Current Limit and Soft Start
- . Input over voltage protection(OVP)
- <1µA Shutdown Current
- . SOT23-5 package

### **APPLICATIONS**

- . Cellular and Smart Phones
- . Wireless and DSL Modems
- PDAs
- . Portable Instruments
- . Digital Still and Video Cameras
- PC Cards

# **TYPICAL APPILCATION**

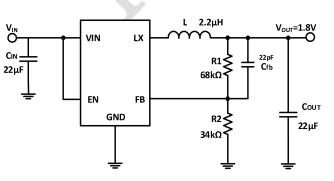


Figure 1. Basic Application Circuit

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# **GENERAL DESCRIPTION**

The STI3411A is a 1.0MHz constant frequency, current mode step-down converter. It is ideal for portable equipment requiring very high current up to 2A from single-cell Lithium-ion batteries while still achieving over 90% efficiency during peak load conditions. The STI3411A also can run at 100% duty cycle for low dropout operation, extending battery life in portable systems while light load operation provides very low output ripple for noise sensitive applications. The STI3411A can supply up to 2A output load current from a 2.5V to 6V input voltage and the output voltage can be regulated as low as 0.6V. The high switching frequency minimizes the size of external components while keeping switching losses low. The internal slope compensation setting allows the device to operate with smaller inductor values to optimize size and provide efficient operation. The STI3411A is offered in a 5-pin, SOT package, and is available in an adjustable version.

This device offers two operation modes, PWM control and PFM Mode switching control, which allows a high efficiency over the wider range of the load

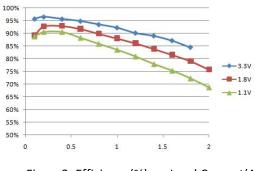


Figure2. Efficiency(%) vs. Load Current(A)

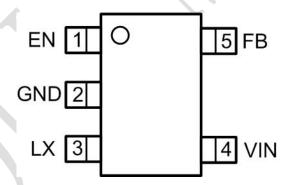
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# ABSOLUTE MAXIMUM RATINGS (Note 1)

Parameter	Value	Unit
Input Supply Voltage	-0.3~6.5	V
LX Voltages	-0.3~6.5	V
EN,FB Voltage	-0.3~6.5	V
LX Voltage (<10ns transient)	-2.5~7	V
LX Voltage (<5ns transient)	-3.5~7.5	v
Storage Temperature Range	-65~150	°C
Junction Temperature(Note2)	160	°C
Power Dissipation	600	mW
Lead Temperature(Soldering,10s)	260	°C

# PACKAGE/ORDER INFORMATION



SOT23-5

### Top Mark: S15BXXX (S15B: Device Code, XXX: Inside Code)

Part Number	Package	Top mark	Quantity/ Reel
STI3411A	SOT23-5	S15BXXX	3000





# **PIN DESCRIPTION**

Pin	Name	Function
1	EN	Chip Enable Pin. Drive EN above 1.5V to turn on the part. Drive EN below 0.3V to turn it off. Do not leave EN floating.
2	GND	Ground pin.
3	LX	Power Switch Output. It is the switch node connection to Inductor. This pin connects to the drains of the internal P-ch and N-ch MOSFET switches.
4	VIN	Power supply input pin.
5	FB	Output Voltage Feedback Pin.

#### **ESD RATING**

Items	Description	Value	Unit
V <sub>ESD</sub>	Human Body Model for all pins	±2000	V

#### JEDEC specification JS-001

# **RECOMMENDED OPERATING CONDITIONS**

Items	Description	Min	Max	Unit
Voltage Range	IN	2.5	6	V
ТА	Operating Temperature Range	-40	85	°C



# ELECTRICAL CHARACTERISTICS (Note 3)

#### ( V<sub>IN</sub>=V<sub>EN</sub>=3.6V ,V<sub>OUT</sub>=1.8V , T<sub>A</sub> = 25°C, unless otherwise noted.)

Parameter	Conditions	Min	Тур	Max	Unit
Input Voltage Range		2.5		6	V
OVP Threshold			6.5		V
UVLO Threshold		1.7	1.9	2.1	V
Quiescent Current	V <sub>EN</sub> =2.0V, I <sub>OUT</sub> =0, V <sub>FB</sub> =V <sub>REF</sub> *105%		40	75	μA
Shutdown Current	V <sub>EN</sub> =0V		0.1	1.0	μA
	T <sub>A</sub> = 25°C	0.588	0.600	0.612	V
Regulated Feedback Voltage VFB	$T_A = 0^{\circ}C \le T_A \le 85^{\circ}C$	0.586	0.600	0.613	V
	$T_A = -40^{\circ}C \le T_A \le 85^{\circ}C$	0.585	0.600	0.615	V
Reference Voltage Line Regulation	V <sub>IN</sub> =2.5V to 5.5V		0.1		%/V
Output Voltage Accuracy	V <sub>IN</sub> = 2.5V to 5.5V, I <sub>OUT</sub> =10mA to 2000mA	-3		+3	%
Output Voltage Load Regulation	Iout=10mA to 2000mA		0.2		%/A
Oscillation Frequency	V <sub>OUT</sub> =100%			MHz	
	V <sub>OUT</sub> =0V		1.0 300		kHz
On Resistance of PMOS	I <sub>LX</sub> =100mA		150		mΩ
On Resistance of NMOS	I <sub>LX</sub> =-100mA		70		mΩ
Peak Current Limit	V <sub>IN</sub> = 5V, V <sub>OUT</sub> =90%		2.5		А
EN Threshold		0.30	1.0	1.50	V
EN Leakage Current			±0.01	±1.0	μA
LX Leakage Current	V <sub>EN</sub> =0V,V <sub>IN</sub> =V <sub>LX</sub> =5V		±0.01	±1.0	μA

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2:  $T_J$  is calculated from the ambient temperature  $T_A$  and power dissipation  $P_D$  according to the following formula:  $T_J = T_A + (P_D) \times (250^{\circ}C/W)$ .

Note 3: 100% production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization.

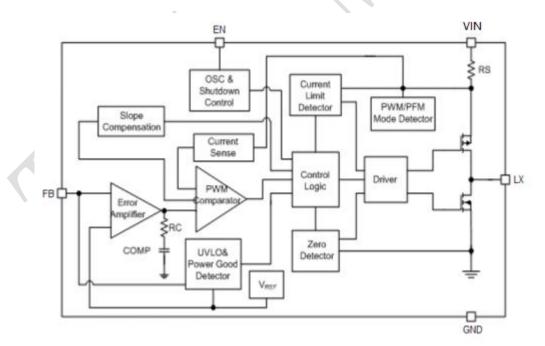


#### **OPERATION**

The STI3411A is a high output current monolithic switch mode step-down DC-DC converter. The device operates at a fixed 1.0MHz switching frequency, and uses a slope compensated current mode architecture.

This step-down DC-DC converter can supply up to 2A output current at VIN = 5.0V and has an input voltage range from 2.5V to 6V. It minimizes external component size and optimizes efficiency at the heavy load range. The slope compensation allows the device to remain stable over a wider range of inductor values so that smaller values ( $2.2\mu$ H to  $10\mu$ H) with lower DCR can be used to achieve higher efficiency. Only a small bypass input capacitor is required at the output.

The adjustable output voltage can be programmed with external feedback to any voltage, ranging from 0.6V to near the input voltage. It uses internal MOSFETs to achieve high efficiency and can generate very low output voltages by using an internal reference of 0.6V. At dropout operation, the converter duty cycle increases to100% and the output voltage tracks the input voltage minus the low RDS(ON) drop of the P-channel high-side MOSFET and the inductor DCR. The internal error amplifier and compensation provides excellent transient response, load and line regulation. Internal soft start eliminates any output voltage overshoot when the enable or the input voltage is applied.



# FUNCTIONAL BLOCK DIAGRAM

Figure 3. STI3411A Block Diagram

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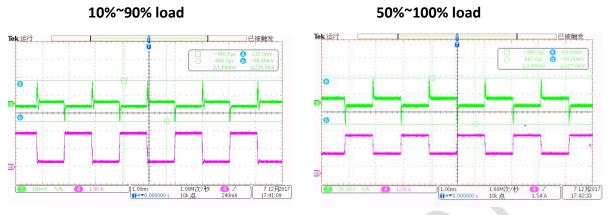




# **FUNCTIONAL TEST**

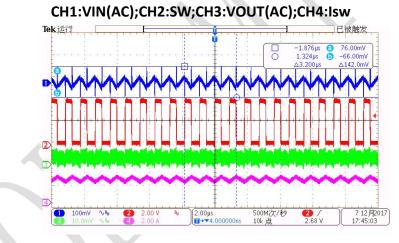
Test condition: Vin=5V,Vout=1.8V;

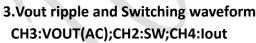
#### **1.Load Dynamic Response**



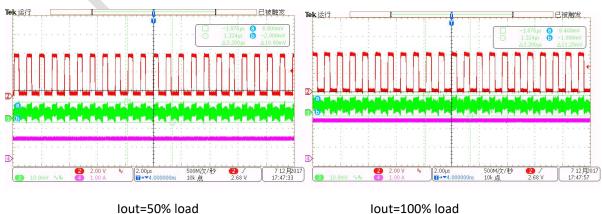
Vin=5V, Vout=1.8V Load transient((0.2A-1.8A-0.2A) Vin=5V, Vout=1.8VLoadtransient((0.2A-1.8A-0.2A)

# 2.Input/output ripple, lout=full load





#### CH3:VOUT(AC);CH2:SW;CH4:lout

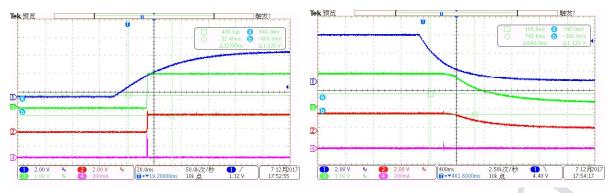


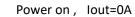
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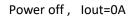


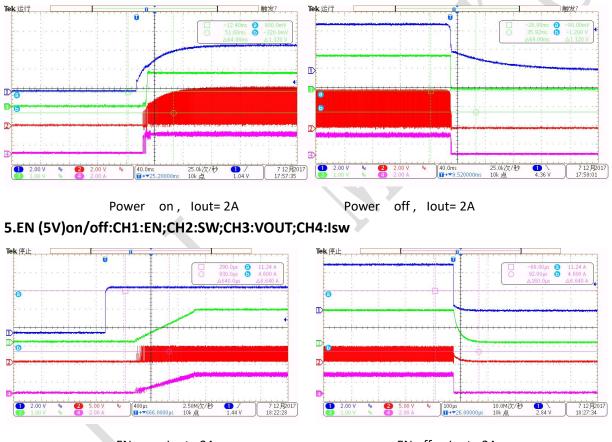
# STI3411A

#### 4.Power on/off: CH1:VIN;CH2:SW;CH3:VOUT;CH4:Isw









EN on , lout= 2A

EN off , lout= 2A



# **APPLICATION INFORMATION**

#### Setting the Output Voltage

Figure 1 shows the typical application circuit for the STI3411A. The STI3411A can be externally programmed. Resistors R1 and R2 in Figure 1 program the output to regulate at a voltage higher than 0.6V. To limit the bias current required for the external feedback resistor string while maintaining good noise immunity, the minimum suggested value for R2 is  $59k\Omega$ . Although a larger value will further reduce quiescent current, it will also increase the impedance of the feedback node, making it more sensitive to external noise and interference. Table 1 summarizes the resistor values for various output voltages with R2 set to either 59k $\Omega$  for good noise immunity or 316k $\Omega$  for reduced no load input current. The external resistor sets the output voltage according to the following equation:

$$V_{OUT} = 0.6 \times (1 + \frac{R_1}{R_2})$$

$$R_1 = (V_{OUT} / 0.6 - 1) \times R_2$$

#### **Inductor Selection**

For most designs, the STI3411A operates with inductors of 1µH to 4.7µH. Low inductance values are physically smaller but require faster switching, which results in some efficiency loss. The inductor value can be derived from the following equation:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times f_{OSC}}$$

Where  $\Delta I_L$  is inductor Ripple Current. Large value inductors result in lower ripple current

and small value inductors result in high ripple current. For optimum voltage-positioning load transients, choose an inductor with DC series resistance in the  $50m\Omega$  to  $150m\Omega$  range.

#### **Input Capacitor Selection**

The input capacitor reduces the surge current drawn from the input and switching noise from the device. The input capacitor impedance at the switching frequency should be less than input source impedance to prevent high frequency switching current passing to the input. A low ESR input capacitor sized for maximum RMS current must be used. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients. A 22µF ceramic capacitor for most applications is sufficient. A large value may be used for improved input voltage filtering.

#### **Output Capacitor Selection**

The output capacitor is required to keep the output voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their

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low ESR and high ripple current ratings. The output ripple  $\triangle V_{OUT}$  is determined by:

$$\Delta V_{OUT} \leq \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{OSC} \times L} \times \left( ESR + \frac{1}{8 \times f_{osc} \times C3} \right)$$

A 22µF ceramic can satisfy most applications.

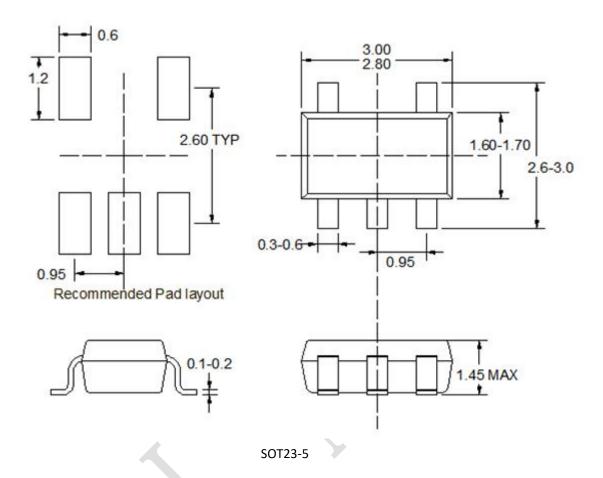
#### Layout Consideration

When laying out the printed circuit board, the following checking should be used to ensure proper operation of the STI3411A. Check the following in your layout:

- 1. The power traces, consisting of the GND trace, the LX trace and the VIN trace should be kept short, direct and wide.
- 2. Does the (+) plates of Cin connect to Vin as closely as possible. This capacitor provides the AC current to the internal power MOSFETs.
- 3. Keep the switching node, LX, away from the sensitive VOUT node.
- 4. Keep the (-) plates of Cin and Cout as close as possible



# **PACKAGE INFORMATION**



Note:

- 1) All dimensions are in millimeters.
- 2) Package length does not include mold flash, protrusion or gate burr.
- 3) Package width does not include inter lead flash or protrusion.
- 4) Lead popularity (bottom of leads after forming) shall be 0.10 millimeters max.
- 5) Pin 1 is lower left pin when reading top mark from left to right,